

# Photo IC

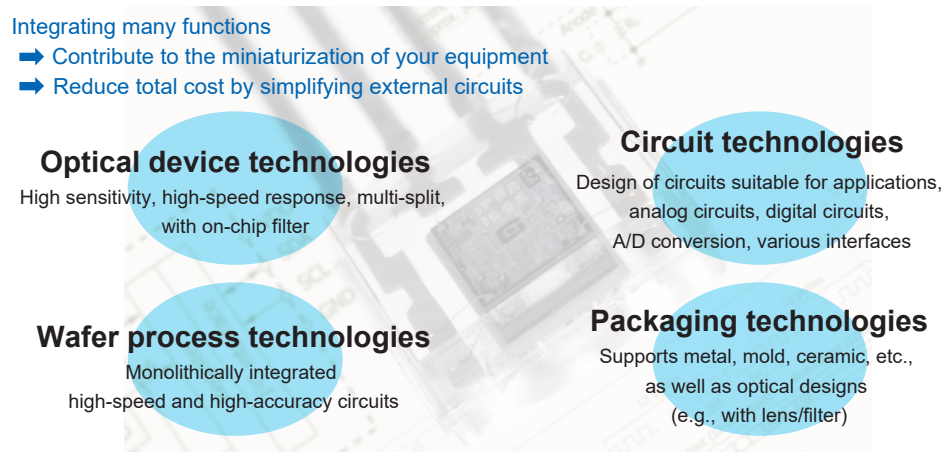
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# What is a photo IC?

Photo ICs are optical devices that combine an opto-semiconductor and a signal processing circuit into one package. Hamamatsu combines optical device technology, circuit technology, wafer process technology, and packaging technology to develop and manufacture photo ICs suitable for a variety of applications.

We have established a consistent production system from circuit / package design to wafer process, assembly and inspection, and we also conduct various analysis and evaluations including reliability. We also offer photo ICs with custom specifications to suit your requests.



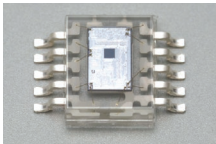
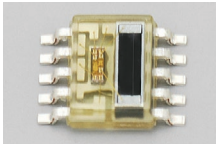
## • Features

Photo ICs offer the following features compared to circuits configured with discrete parts:

- Compact and lightweight
- Resistant to electromagnetic induction noise
- High reliability
- Excellent mass productivity
- High cost performance

## • Classification of Photo ICs

There are two types of photo ICs, monolithic and hybrid.

Type	Features	
Monolithic type photo IC	Forming the photosensor and signal processing circuit on the same chip 	<ul style="list-style-type: none"><li>• Compact size</li><li>• Resistant to noise and not affected by unnecessary parasitic parameters due to the short wiring that connects a photosensor and a signal processing circuit ➡ Stable operation</li></ul>
Hybrid type photo IC	Connecting the photosensor and signal processing circuit in one package 	<ul style="list-style-type: none"><li>• Photosensor's shape and characteristics can be easily changed (high degree of design freedom is possible)</li><li>• Combination with a light emitter (LED, etc.) available</li></ul>

## • Applications

Hamamatsu photo ICs are used in a variety of applications, including ambient light (illuminance and color) detection, plastic optical fiber communications, optical switches, encoders, etc. We can also provide photo ICs that meet FA and automotive standards.



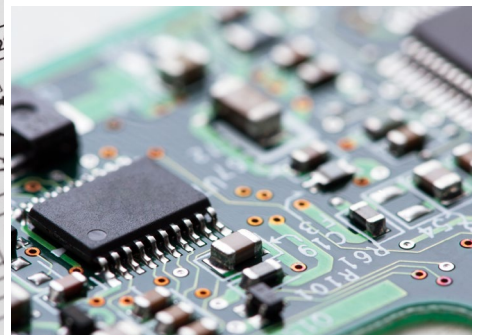
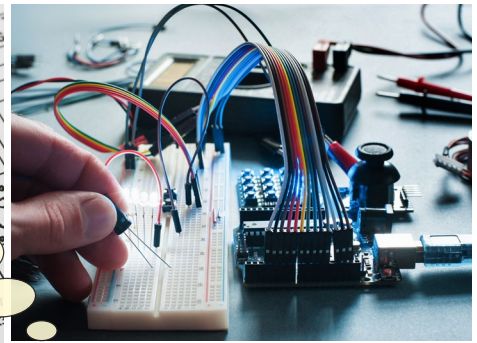
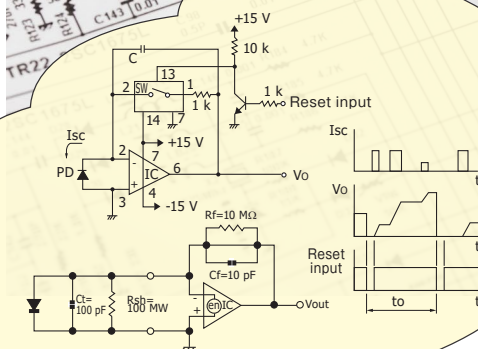


# Custom products available

Hamamatsu accepts custom orders for photo ICs that makes use of our extensive experience and knowledge of opto-semiconductors. In addition to adding functions, increasing reliability, and reducing costs, we can also offer alternatives to discontinued products from other manufacturers.

## Do you have any concerns or requests such as those below?

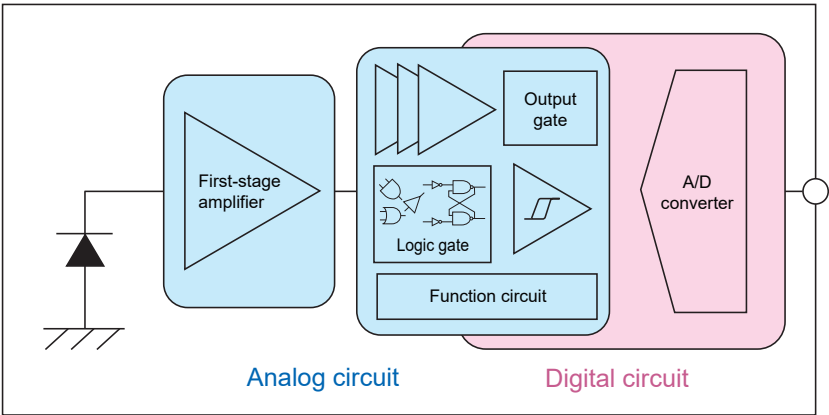
- You don't know how to use opto-semiconductors
- You don't know what type of detection circuit is optimal
- Your circuit is not stable
- You want to reduce mounting space
- You want to reduce the number of components
- Your circuit oscillates
- You want to know how to select components
- You want to add a function
- Another manufacturer's product has been discontinued
- Noise suppression is a problem
- You want to reduce power consumption
- There are many parameters and you cannot grasp them
- Formulas are difficult
- You can't achieve the desired characteristics



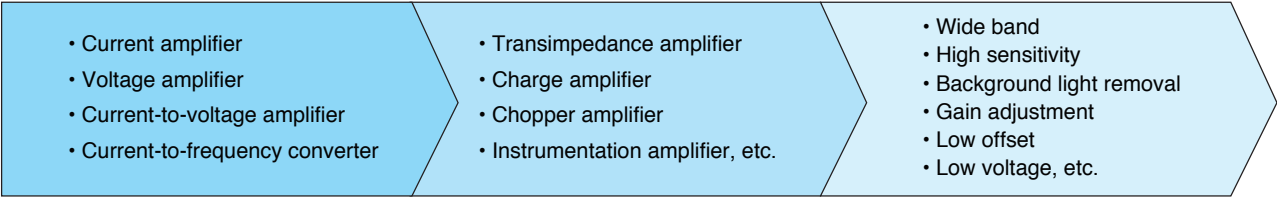
**We offer photo ICs with custom specifications  
to suit your requests**

• **Circuit technologies**

With a wealth of knowledge about photosensors, Hamamatsu can design circuits to meet your requirements. In addition to the first-stage amplifier suitable for the photosensors, we support analog circuits and digital circuits.



■ **First-stage amplifier**

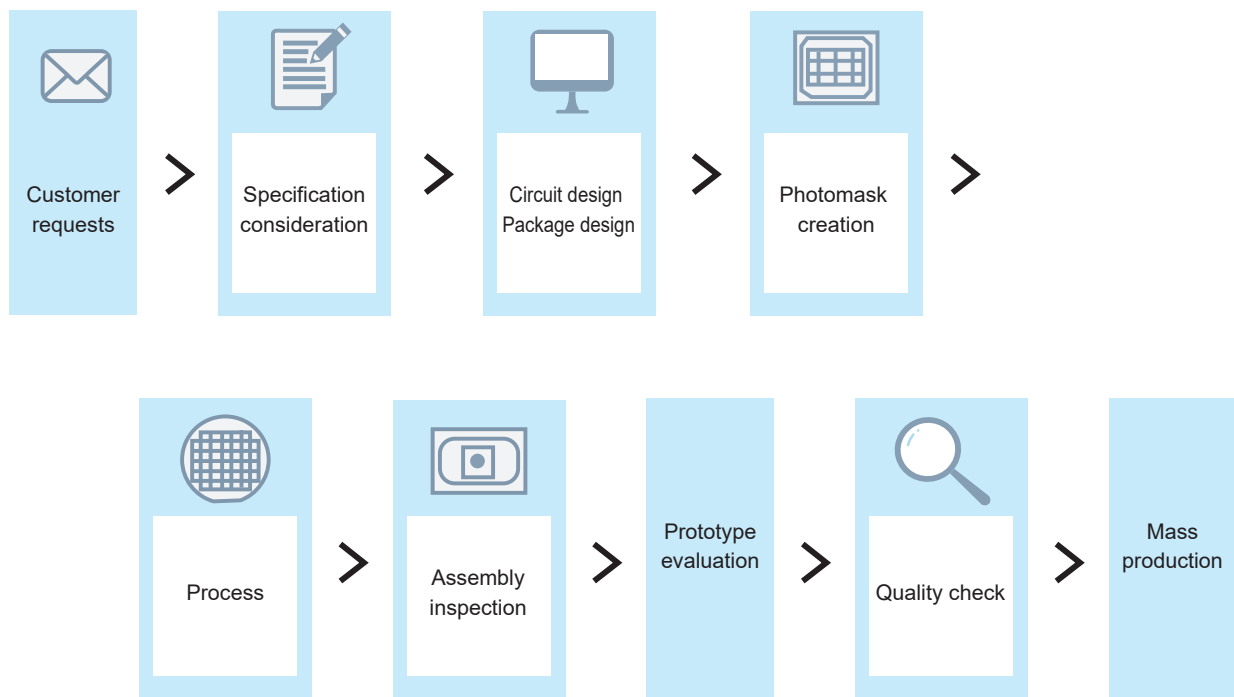


■ **Circuit example**

Comparator	<ul style="list-style-type: none"><li>• Wide band</li><li>• With hysteresis</li></ul>	Input/output interface	<ul style="list-style-type: none"><li>• TTL</li><li>• CMOS</li><li>• LVDS</li><li>• PECL</li><li>• CML</li></ul>
Filter	<ul style="list-style-type: none"><li>• Active filter</li><li>• Low-pass filter</li><li>• High-pass filter</li></ul>	Signal processing	<ul style="list-style-type: none"><li>• Various logic gates</li><li>• Counter</li><li>• Timer circuit</li><li>• Oscillator</li><li>• Timing generator</li><li>• A/D converter</li></ul>
Detection circuit	<ul style="list-style-type: none"><li>• Edge detection circuit</li><li>• Sample hold circuit</li><li>• Peak detection circuit</li><li>• Bottom detection circuit</li></ul>	Serial communication interface	<ul style="list-style-type: none"><li>• I<sup>2</sup>C</li><li>• SPI</li></ul>
Voltage amplifier	<ul style="list-style-type: none"><li>• Buffer amplifier</li><li>• Linear amplifier</li><li>• Limiting amplifier</li></ul>	◇ Laser trimming process can correct for characteristic variations	
Other circuits	<ul style="list-style-type: none"><li>• Temperature detection circuit</li><li>• Light level monitor circuit</li><li>• LED driver circuit</li></ul>		
Power supply system	<ul style="list-style-type: none"><li>• Reference voltage source</li><li>• Current source</li><li>• Regulator</li></ul>		
Output method	<ul style="list-style-type: none"><li>• Open drain</li><li>• Open collector</li></ul>		

## - Procedural flow from custom order to delivery

Hamamatsu has established a comprehensive production system ranging from photo IC design to wafer process, assembly, inspection, and mass production at our ISO9000 and ISO14000 compliant domestic factories. We also offer strong support for various analyses and evaluation systems such as reliability testing.



Main Factory  
(Si process, MEMS process,  
module manufacturing)



Mitsue Factory  
(Assembly)



Shingai Factory  
(Assembly)

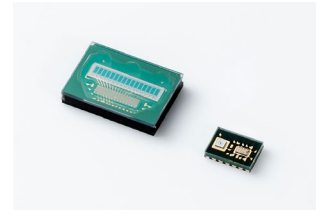


Miyakoda Factory  
(Compound process,  
semiconductor laser  
manufacturing)

# Photo IC product examples

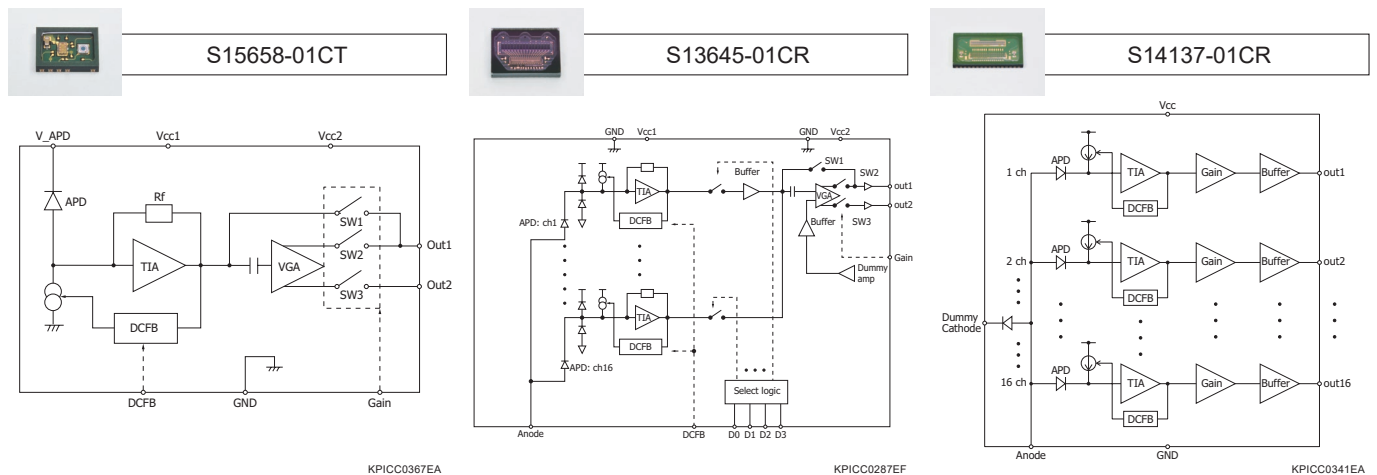
Ideal for detecting pulse signals

## Photosensors with front-end IC



These are photo ICs in which an APD and transimpedance amplifiers (TIAs) are integrated. They achieve high sensitivity, low noise, and high-speed response, making them suitable for distance measurement. They consist of our APD and our unique circuit, and adopt a design that is not easily affected by the usage environment such as background light. They are hybrid type photo ICs and can be used for custom products with built-in APD and APD array with different photosensitive area sizes.

### ■ Block diagram



### ► Hamamatsu photo IC technologies

- Transimpedance amplifier to bring out the characteristics of APDs ➡ Optimizes gain and bandwidth
- DC feedback circuit which automatically removes DC offset components generated by TIA ➡ Less susceptible to background light
- Logic circuit for gain switching function
- Circuit technology that achieves a stable output even when excessive light enters the photo IC
- Circuit design to reduce ringing of output waveforms that cause malfunctions when detecting pulse signals
- APD array can be built-in
- Serial output type that outputs from any pixel specified in the selection logic and parallel output type that can measure all pixels simultaneously
- Circuit design with consideration for resistance to high voltages unique to APDs and for effects of element heating on APD characteristics

### ■ Application examples



AGV  
(automated guided vehicle)



Autonomous driving,  
LiDAR

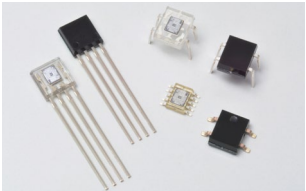


Robot cleaner



Laser rangefinder

Enables object detection  
with few malfunctions even under background light



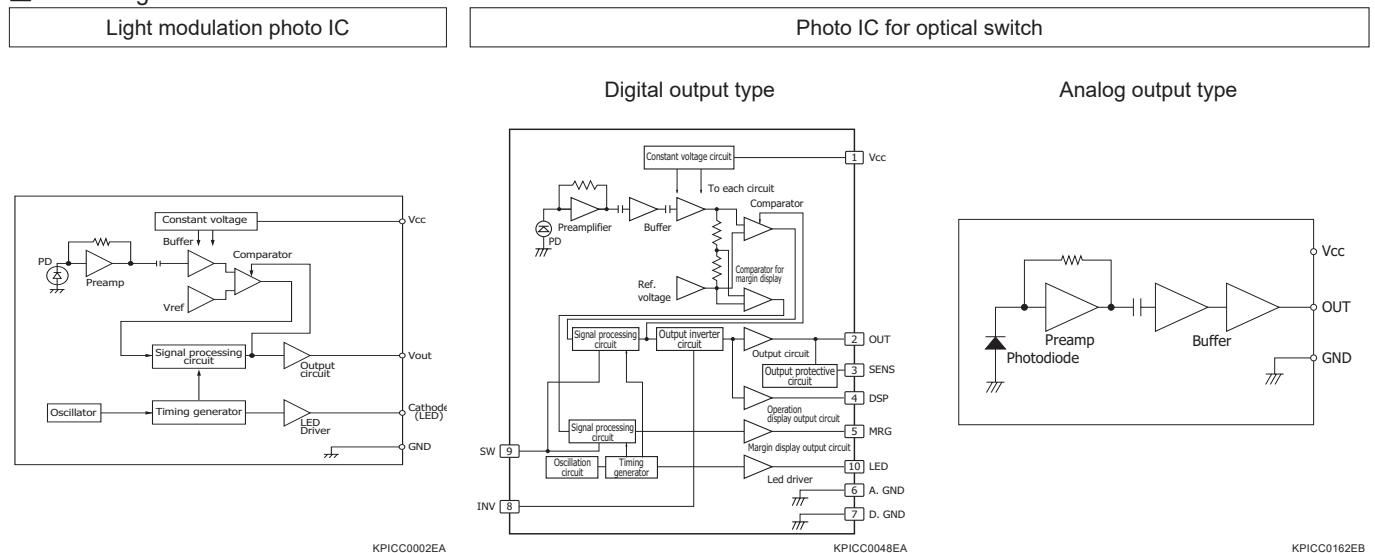
## Light modulation photo IC • Photo IC for optical switch

These are photo ICs that can detect objects with high sensitivity and few malfunctions even under background light. By connecting LED, they can be used as a transmissive type (photointerruptor) or reflective type (photoreflexor) optical switches that combine a photosensor and a light emitter.

In addition to background light countermeasures, light modulation photo ICs • Photo IC for optical switch employ a synchronous detection method that pulse-modulates the signal light and detects the signal in synchronization with that timing. This reduces the effect of noise from light entering asynchronously.

They are monolithic type photo ICs, and a photodiode and an amplifier are connected within the chip, minimizing the effects of parasitic parameters and noise on amplifier performance. Photo ICs for optical switches are available in digital and analog output types.

### ■ Block diagram



### ► Hamamatsu photo IC technologies

- **Preamplifier (AC amplifier circuit)** with expanded dynamic range for DC and low frequency background light without impairing signal detection sensitivity
- **Capacitance coupling** to remove the effects of low-frequency background light and the DC offset of the preamplifier
- **Comparator with hysteresis** to prevent chattering (malfunction) caused by minute fluctuations in incident light
- **Oscillator** and **timing generator** that synchronize the timing of LED drive and digital signal processing
- **Dedicated logic circuit (signal processing circuit)** for synchronous detection
- **LED drive circuit (open collector drive)** that drives external LED by LED driving pulses generated in timing generators

### ■ Application examples



Safety light curtain

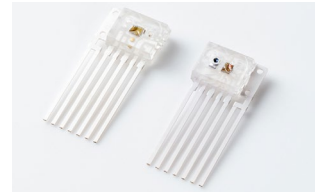


Auto faucet



## Achieves low-cost optical link systems

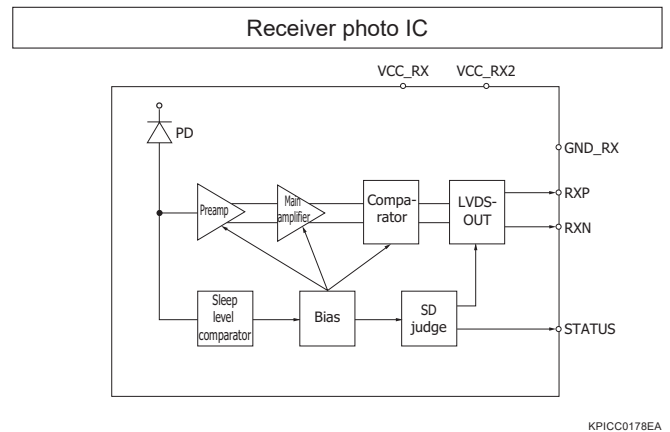
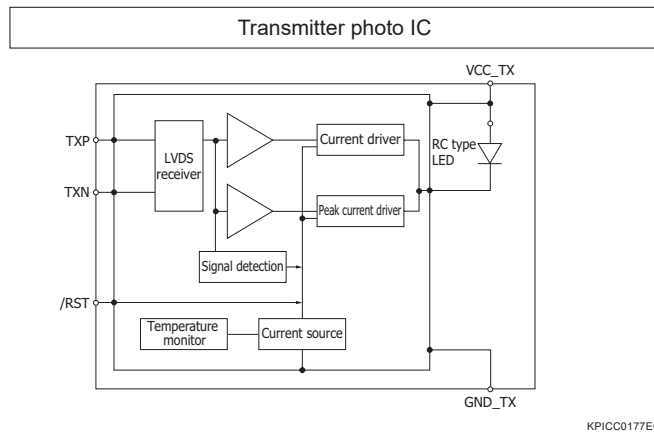
# Photo IC for optical link



These are transmitter/receiver photo ICs for plastic optical fiber communications. The transmitter photo ICs are equipped with an LED with a wavelength of 650 nm and a drive IC with a temperature compensation function. They support a wide operating temperature range and provide stable light output. The receiver photo ICs consist of a Si PIN photodiode and a signal processing circuit. The adoption of a fully differential structure using a dummy photodiode reduces the effects of external noise, achieving high sensitivity. It has a sleep function that reduces power consumption during a waiting time, and switches to standby mode when there is no input.

To customize these photo ICs, select an LED and a Si photodiode to match the fiber you are using. Customization is possible for both hybrid types and monolithic types. In addition, optical transceiver types are available.

### ■ Block diagram



### ► Hamamatsu photo IC technologies

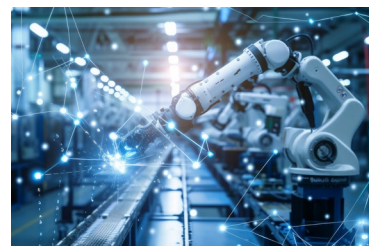
- Peaking circuit to correct the light output waveform response
- Temperature sensing circuit and LED driver circuit to correct LED temperature fluctuations
- Low distortion circuit with stable output for temperature/supply voltage fluctuations
- Fully differential circuit (dummy photodiode is used to eliminate external noise and power supply noise)

- Transimpedance amplifiers with optimized gain and band
- Signal detection circuit for sleep function
- Power supply isolation to avoid “swinging back” on the power line that causes jitter
- Supports output interfaces such as LVDS, PECL, and CML

### ■ Application examples



In-vehicle network



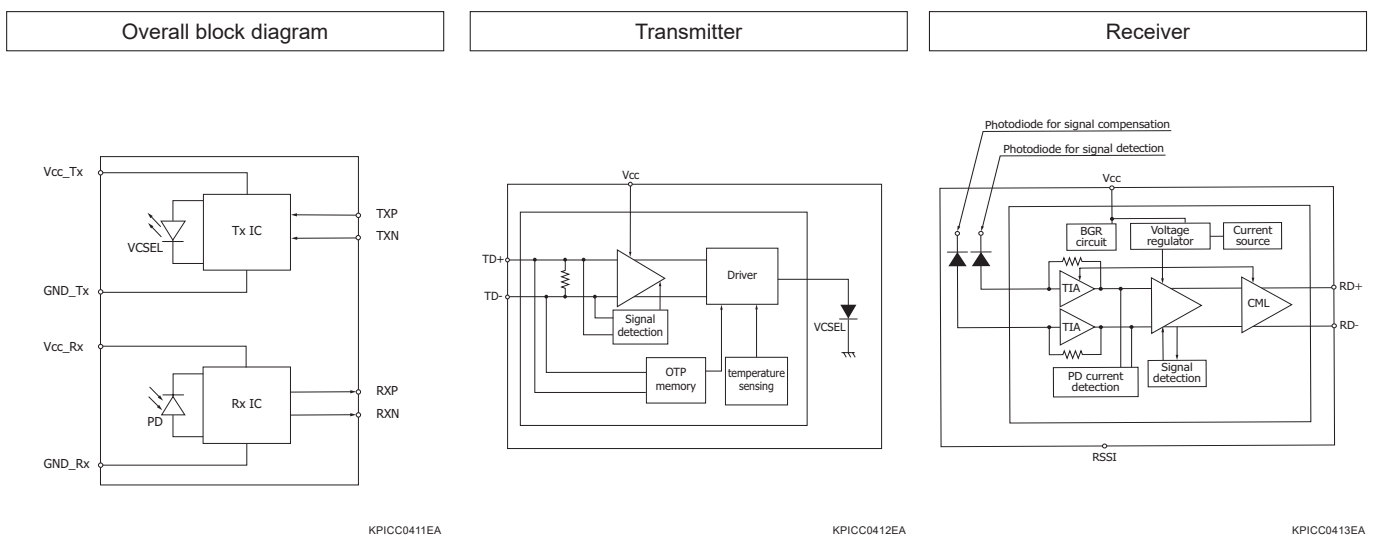
Communication between devices



## Optical transceiver P16548-01AT

This optical transceiver is capable of free-space optical data communication. By placing two of this product facing each other on the optical axis, full-duplex two-way communication with a transmission distance of up to 100 mm is realized. Maximum data rate is 1.25 Gbps, and this characteristic is maintained even when communicating between a 360° rotating object and stationary object. This product also has a built-in transmitter and receiver. For the transmitter we use a 850 nm VCSEL, and by combining it with a driver IC that can compensate for temperature, it is possible to do stable communication over a wide operating temperature range. The receiver consists of a PIN photodiode and a signal processing IC, and is capable of high-speed operation.

### ■ Block diagram



### ► Hamamatsu photo IC technologies

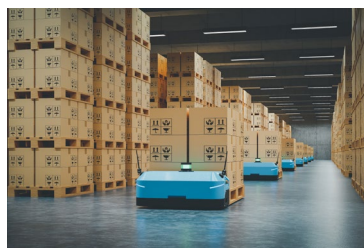
- The driver IC with built-in [OTP memory](#) sets the drive current corresponding to the element variation and temperature characteristics of the VCSEL
- [Fully differential circuit](#) (dummy photodiode is used to eliminate external noise and power supply noise)
- Signal detection circuit for testing signal presence/absence
- [RSSI function](#) that can monitor the amount of light received into the photodiode
- The receiver consists of a PIN photodiode and a signal processing IC, enabling [signal transmission up to 1.25 Gbps](#)
- [CML interface](#) capable of high-speed communication

### ■ Application examples

#### Communication between devices



Communication between  
robot control



Communication between  
AMR and AGV



Communication between  
cameras

Two-terminal sensors as easy to use as photodiodes,  
capable of high-current output

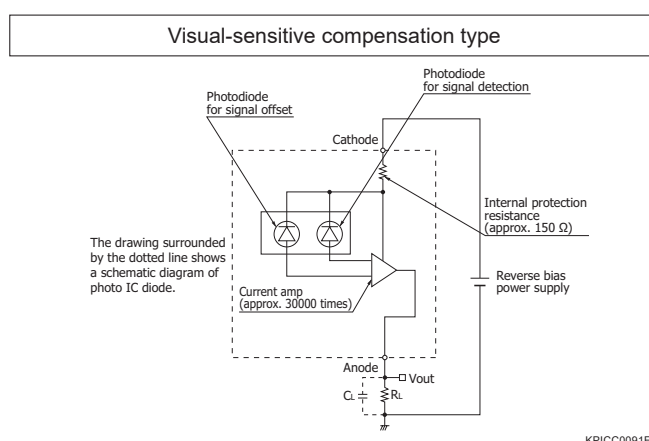
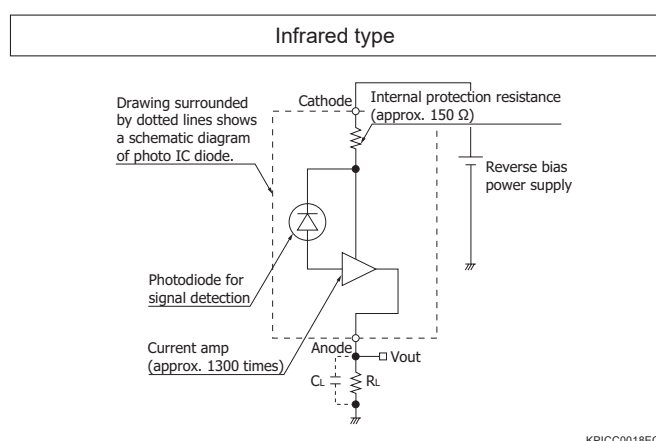
## Photo IC diodes



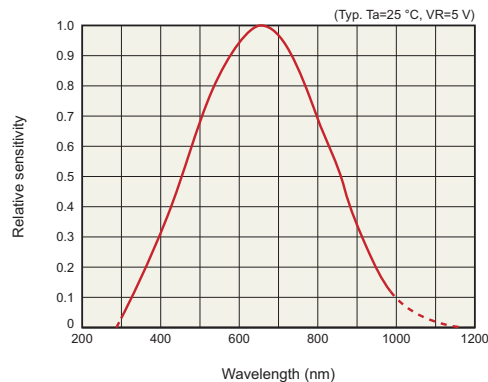
These photo ICs amplify and output the photocurrent generated by a photodiode. Highly sensitive and stable operation is possible, and they can be used in the same way as reverse-biased photodiodes.

Two types are available, infrared type and visual-sensitive compensation type. The visual-sensitive compensation type consists of two photodiodes with different on-chip filters and a current amplifier (subtracted amplifier circuit). They achieve spectral response close to human eye sensitivity and can be used as illuminance sensors.

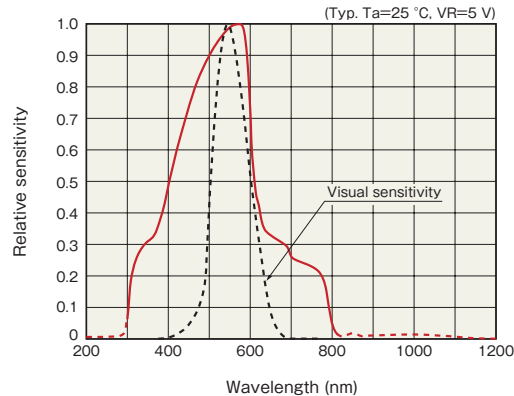
### ■ Block diagram



### Spectral response example



### Spectral response example



### ► Hamamatsu photo IC technologies

- **Current amplifier** realizing a wide operating temperature range and highly sensitive, stable operation
- **Subtraction amplifier circuit** for spectral response close to human eye sensitivity in combination with on-chip filters

### ■ Application examples



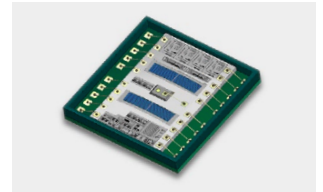
Automatic lighting



Auto lights in automobiles

## For optical encoders

## Photo IC for encoder



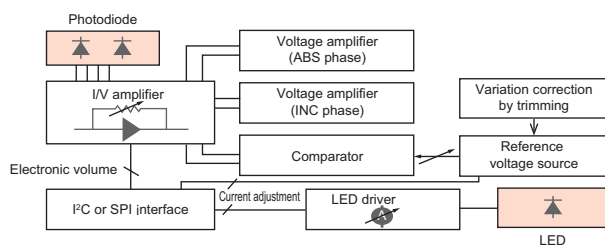
These are photo ICs for configuring optical encoders. The following customization is available to meet your encoder specifications:

- Special photodiode pattern
- Emitter/receiver integrated type combining a photodiode and an LED
- Reduced mounting space realized by miniaturization (monolithic type)
- I<sup>2</sup>C interface

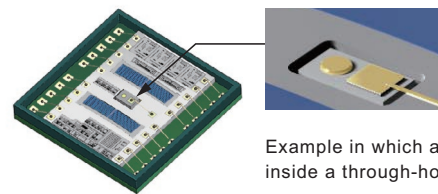
## ■ Custom example

## LED integrated photo IC (monolithic type)

## Block diagram

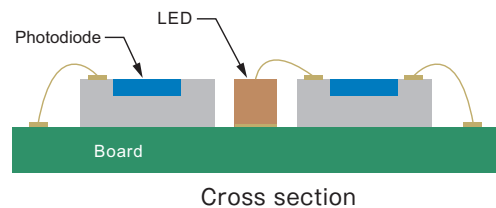
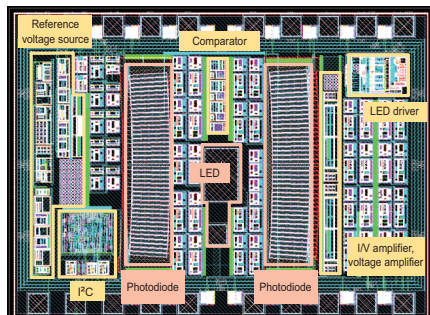


## Product image



Example in which an LED is mounted inside a through-hole of a Si photodiode

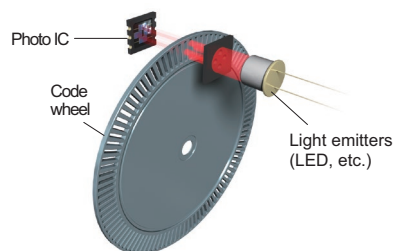
## Chip



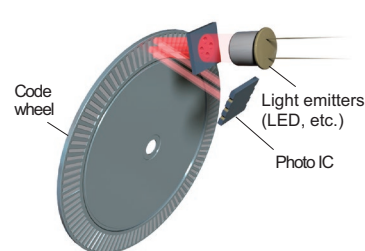
## ► Hamamatsu photo IC technologies

- Detection circuit (preamplifier) to detect rotation/position/speed
- Analog output (amplifier output) or digital output (comparator output)
- I²C interface or SPI for multifunction capability

## ■ Application examples



Transmissive encoder



Reflective encoder

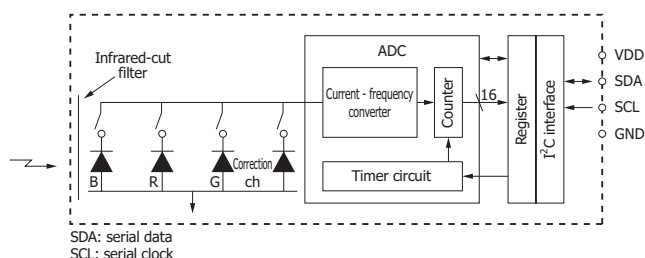


## Information transfer between ICs via two signal lines

I<sup>2</sup>C-compatible color sensors

These are color sensors compatible with I<sup>2</sup>C (Inter-Integrated Circuit) interface. They have a built-in photodiode with an on-chip filter that is sensitive to Red ( $\lambda_p=615$  nm), Green ( $\lambda_p=530$  nm), and Blue ( $\lambda_p=460$  nm) lights. The I<sup>2</sup>C interface can be connected to a microcontroller. The detection results are output with a 16-bit digital value for each color. The sensitivity and integration time are adjustable so that photometry can be performed under a variety of conditions.

## ■ Block diagram



KPIC00152EB

## ► Hamamatsu photo IC technologies

- Photometry over a wide dynamic range
- Square wave output with oscillation frequency proportional to incident light level (duty ratio: 50%), current-to-frequency conversion circuit that can be directly connected to the logic circuit input
- Timer circuit with built-in oscillator outputting internal clock and integration time
- Counter circuit that counts the output frequency within the integration time
- A/D converter that converts detection results to 16-bit digital values
- Register circuit to store counter data and I<sup>2</sup>C interface data
- I<sup>2</sup>C interface for transmitting and receiving data to and from the outside

## ■ Application examples



Backlight monitor (backlight dimming)



Printer printing monitor

Information described in this material is current as of June 2025.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

# HAMAMATSU

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